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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Barbara A. Haselden and John Lee
Assignee: ProMOS Technologies, Inc.
Title: Two Stage Etching Of Silicon Nitride To Form A Nitride Spacer
Application No.: 10/800,190 Filing Date: March 12, 2004
U.S. Patent No.: 6,846,730 B2 Issue Date: January 25, 2005
Examiner: Michael Tokar Group Art Unit: 2829
Docket No.: M-12473-1D US

San Jose, California
September 1, 2005

Attn: Certificate of Correction Branch
Commissioner For Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Certificate
SEP 12 2005
of Correction

PETITION FOR ENTRY OF CERTIFICATE OF CORRECTION

Sir:

Please enter the enclosed Certificate of Correction (Form PTO 1050) in the above patent. The errors sought to be corrected were made by the Patent and Trademark Office. Thus, no fee is required for the Certificate of Correction pursuant to 37 C.F.R. § 1.322. However, the Commissioner is hereby authorized to charge any fee which may be required for this correction to Deposit Account No. 50-2257.

Please direct all inquiries concerning this request to the undersigned attorney at (408) 392-9250. This form is submitted in duplicate.

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Certificate of Correction Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on September 1, 2005.

David W. Heid

Attorney for Applicant(s)

9/01/05
Date of Signature

Respectfully submitted,

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**UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION**

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APPLICATION NO.: 10/800,190

ISSUE DATE : January 25, 2005

INVENTOR(S) : Barbara A. Haselden and John Lee

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Col. 10, line 47
Delete "15:1" and insert --20:1--.

MAILING ADDRESS OF SENDER (Please do not use customer number below):

MacPherson Kwok Chen & Heid LLP
1762 Technology Drive, Suite 226
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This collection of information is required by 37 CFR 1.322, 1.323, and 1.324. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 1.0 hour to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Attention Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

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